



Product Summary

BV _{DSS}	R _{DS(ON)}	Package	Ι _D T _C = +25°C
650V	$1.4\Omega@V_{GS} = 10V$	ITO220AB (Type TH)	7.7A

Description

This new generation MOSFET features low on-resistance and fast switching, making it ideal for high efficiency power management applications.

Applications

- Motor Control
- Backlighting
- DC-DC Converters
- Power Management Functions

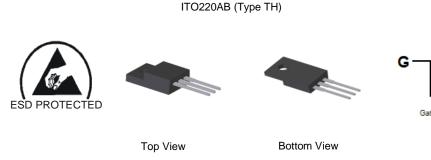
N-CHANNEL ENHANCEMENT MODE MOSFET

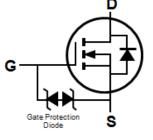
Features

- Low Input Capacitance
- High BV_{DSS} Rating for Power Application
- Low Input/Output Leakage
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

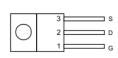
Mechanical Data

- Case: ITO220AB (Type TH)
- Case Material: Molded Plastic, "Green" Molding Compound, UL Flammability Classification Rating 94V-0
- Terminals: Matte Tin Finish Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208
 [®]
- Terminal Connections: See Diagram Below
- Weight: 1.85 grams (Approximate)





Equivalent Circuit



Top View Pin Out Configuration

Ordering Information (Note 4)

Part Number	Case	Packaging
DMG7N65SCTI	ITO220AB (Type TH)	50 pieces/tube

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

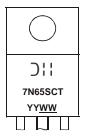
 See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

Notes:



) | | = Manufacturer's Marking 7N65SCT = Product Type Marking Code YYWW = Date Code Marking YY or \underline{YY} = Last Two Digits of Year (ex: 16 = 2016) WW or \underline{WW} = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Units
Drain-Source Voltage			V _{DSS}	650	V
Gate-Source Voltage			V _{GSS}	±30	V
Continuous Drain Current (Notes 5, 8) V_{GS} = 10V	Steady State	$T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$	ID	7.7 4.8	А
Maximum Body Diode Forward Current (Note 5)			Is	10	А
Pulsed Drain Current (10µs pulse, duty cycle = 1%)			I _{DM}	10	A
Avalanche Current, L = 60mH (Note 6)			I _{AS}	1.1	A
Avalanche Energy, L = 60mH (Note 6)			EAS	42	mJ

Thermal Characteristics

Characteristic	Symbol	Value	Units	
Total Power Dissipation (Note 5)	T _C = +25°C	D	28	W
Total Power Dissipation (Note 5)	T _C = +100°C	PD	11	
Thermal Resistance, Junction to Ambient (Note 5)	$R_{ heta}$ JA	45	°C/W	
Thermal Resistance, Junction to Case (Note 5)	R _{0JC}	4.5		
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	650	_	_	V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current	I _{DSS}		_	1	μA	$V_{DS} = 650V, V_{GS} = 0V$	
Gate-Source Leakage	IGSS	_	_	10	μA	$V_{GS} = \pm 24V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	2	—	4	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	1.1	1.4	Ω	$V_{GS} = 10V, I_D = 2.5A$	
Diode Forward Voltage	V _{SD}	_	0.8	1.5	V	$V_{GS} = 0V, I_{S} = 5A$	
DYNAMIC CHARACTERISTICS (Note 6)							
Input Capacitance	C _{iss}		886	_		$V_{DS} = 50V, f = 1.0MHz, V_{GS} = 0$	
Output Capacitance	Coss	_	63	_	pF		
Reverse Transfer Capacitance	Crss	_	8.9	_			
Gate Resistance	RG	_	1.4	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V _{GS} = 10V)	Qg	_	25.2	_		V _{DS} = 480V, I _D = 5A, V _{GS} = 10V	
Gate-Source Charge	Q _{gs}	_	3.5	_	nC		
Gate-Drain Charge	Q _{qd}		12.4	_			
Turn-On Delay Time	t _{D(ON)}	_	10	_			
Turn-On Rise Time	t _R		11	_		$V_{DS} = 300V, R_G = 4.7\Omega, I_D = 2.5A, V_{GS} = 10V$	
Turn-Off Delay Time	t _{D(OFF)}	_	36		ns		
Turn-Off Fall Time	t _F	_	15	_	1		
Body Diode Reverse Recovery Time	t _{RR}	_	271	_	ns		
Body Diode Reverse Recovery Charge	Q _{RR}		1.9	_	μC	$V_{DS} = 60V, I_F = 5A, dl/dt = 100A/\mu s$	

Notes: 5. Device mounted on an infinite heatsink.

Guaranteed by design. Not subject to production testing.
Short duration pulse test used to minimize self-heating effect.

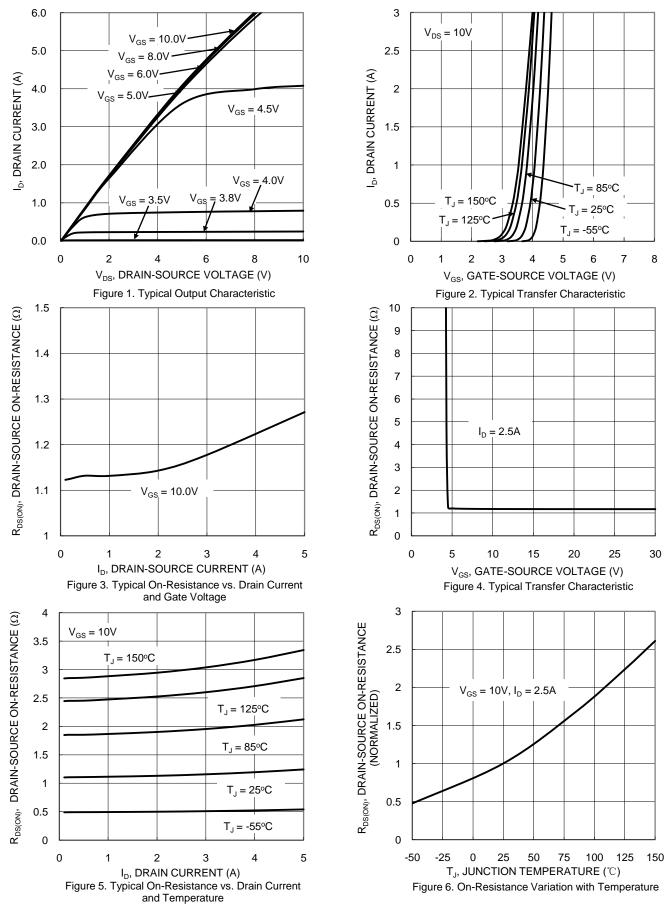
8. Drain current limited by maximum junction temperature.



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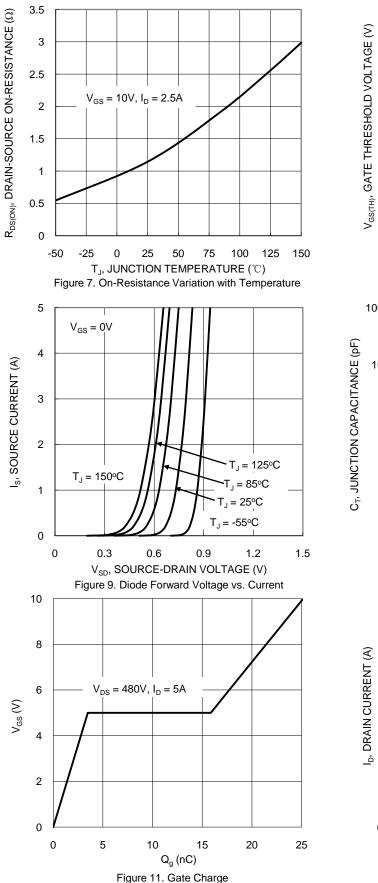
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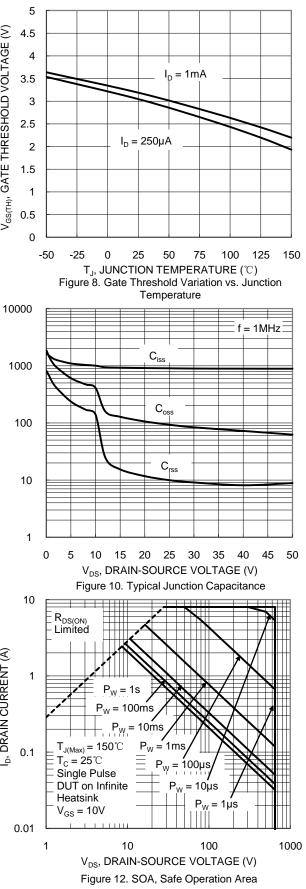


DMG7N65SCTI Document number: DS39329 Rev. 2 - 2

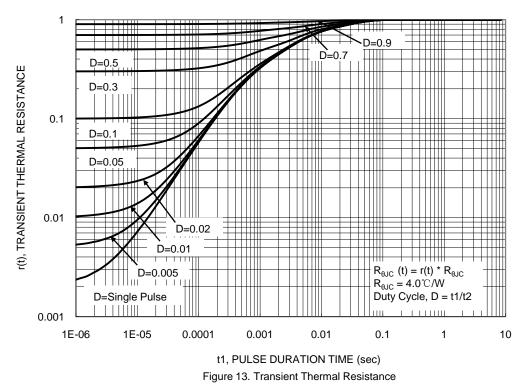


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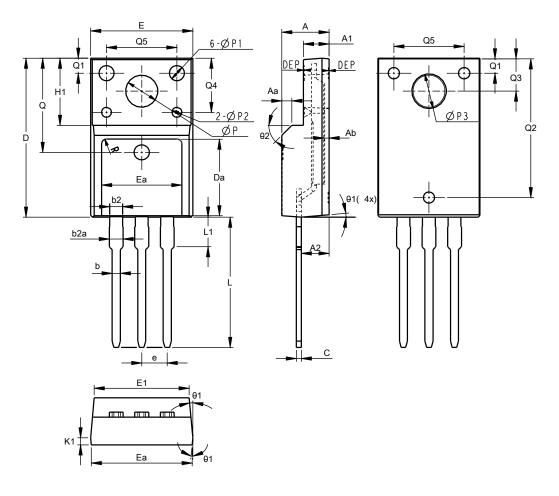




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

ITO220AB (Type TH)



ITO220AB (Type TH)						
Dim	Min	Тур				
Α	4.50	4.90	4.70			
A1	2.34	2.74	2.54			
A2	2.63 2.89		2.76			
Aa	1.00 REF					
Ab	0.30	0.60	0.56			
b	0.75	0.90	0.80			
b2	1.23	1.38	1.28			
b2a	1.25	1.45	1.35			
С	0.45	0.60	0.50			
D	15.47	16.27	15.87			
Da	7.55	8.05	7.80			
е	2.54 BSC					
Е	9.86	10.46	10.16			
E1	9.26	9.66	9.46			
Ea	7.70	8.30	8.00			
Eb	9.76	10.04				
H1	6.70 REF					
L	12.58 13.38		12.98			
L1	2.81	3.05	2.93			
K1	0.65 0.75		0.70			
Q	9	.40 RE	F			
Q1	1.00	2.00	1.50			
Q2	13.50	14.30	13.90			
Q3	3.15	3.45	3.30			
Q4	5.15	5.65	5.40			
Q5	6.70	7.30	7.00			
ØP	3.06	3.40	3.18			
ØP1	1.40	1.60	1.50			
ØP2	0.95	1.05	1.00			
ØP3	3.30	3.60	3.45			
θ1	3º	7°	5⁰			
θ2	-	45°	-			
R		.50 RE				
DEP		0.15	0.10			
All Dimensions in mm						



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